

低压单刀双掷 (SPDT) 模拟开关

UM3157 SC70-6/SC88/SOT363

描述

UM3157 是一款先进的 CMOS 模拟开关，采用硅栅 CMOS 技术制造。该器件在保持 CMOS 低功耗的同时，具备极低的传播延迟和导通电阻。这使其成为便携式和电池供电应用的理想选择。

UM3157 在开关打开时可在电源轨内同样良好地双向传输信号，而在关闭时则可阻断高达电源电平的信号，同时保证先断后连的功能。

该器件的 Select 引脚具有过压保护功能，无论工作电压是多少，都允许该引脚上的电压高于 V_{CC} ，最高可达 6.5V，而不会造成损坏或中断部件的运行。

UM3157 通过改变控制电路的输入缓冲器，只要将控制信号的输入保持在大于 V_{IH} 的最小值和小于 V_{IL} 的最大值，就能保持轨对轨信号的低功耗。因此，该部件可在混合电压轨环境中使用，特别是在手机应用中，可与基带处理器的通用 I/O 直接连接，不再需要将控制输入等同于 V_{CC} ，以保持低功耗。

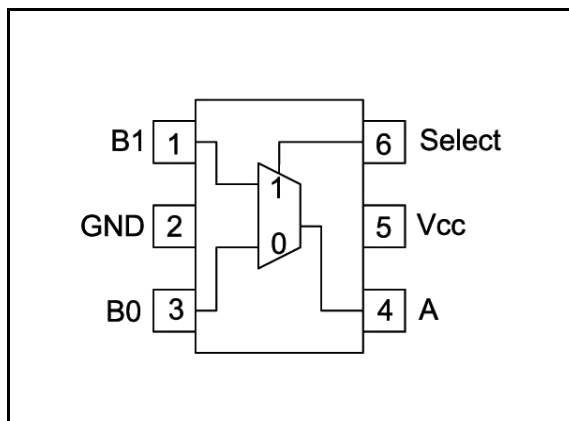
应用

- 采样和保持电路
- 电池供电设备
- 音频和视频信号路由
- 通信电路

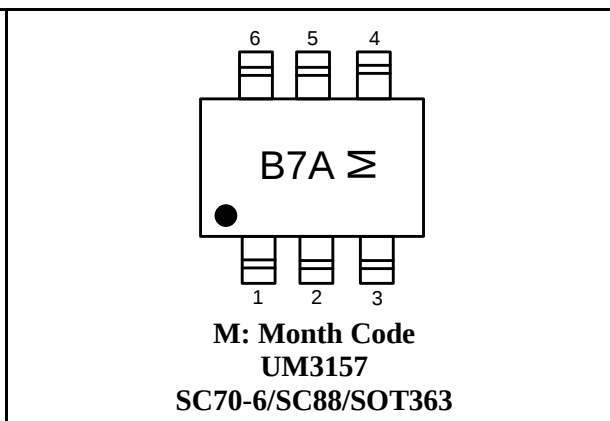
特性

- 控制引脚输入为 5V 耐压
- 低电荷注入
- 极佳的通道间导通电阻匹配
- 低总谐波失真
- 1.65V 至 5.5V 单电源运行
- ESD 性能：
人体放电模型 (HBM) >2kV
机器放电模型 (MM) >200V
- 采用 SC70-6/SC88/SOT363 封装
- 无铅封装

引脚配置



顶部视图



Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty
UM3157	SC70-6/SC88/SOT363	B7A	3000pcs/7 Inch Tape & Reel

Function Table

Select Input	Function
L	B0 Connected to A
H	B1 Connected to A

Absolute Maximum Ratings

Symbol	Parameter	Limit	Unit
V_{CC}	Supply Voltage	-0.5 to +6.5	V
V_S	DC Switch Voltage (Note 1)	-0.5 to ($V_{CC}+0.5$)	
V_{IN}	DC IN Voltage (Note 1)	-0.5 to +6.5	
I_{IK}	DC Input Diode Current @ $V_{IN}<0V$	-50	mA
I_{OUT}	DC Output Current	128	
I_{CC}/I_{GND}	DC V_{CC} or Ground Current	+100	
T_J	Junction Temperature Under Bias	+150	°C
T_{STG}	Storage Temperature	-65 to +150	
T_L	Junction Lead Temperature (Soldering, 10 Seconds)	260	
θ_{JA}	Thermal Resistance	350	°C/W
P_D	Power Dissipation @ +85 °C	180	mW

Note 1: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Ratings (Note 2)

Symbol	Parameter	Limit	Unit
V_{CC}	Supply Voltage Operating	1.65 to 5.5	V
V_{IN}	Switch Input Voltage	0 to V_{CC}	
V_{IN}	Select Input Voltage	0 to V_{CC}	
V_{OUT}	Output Voltage	0 to V_{CC}	
T_A	Operating Temperature	-55 to +125	°C
t_r, t_f	Input Rise and Fall Time Control Input $V_{CC}=2.3V$ to $3.6V$ Control Input $V_{CC}=4.5V$ to $5.5V$	0 to 10 0 to 5.0	ns/V

Note 2: Select input must be held HIGH or LOW, it must not float.

Electrical Characteristics

Symbol	Parameter	Test Conditions	V _{CC} (V)	Temp	Limits (-40 °C to 85 °C)			Unit
					Min	Typ	Max	
DC Electrical Characteristics								
	Analog Signal Range		V _{CC}	Full	0		V _{CC}	V
I _{IN}	Input Leakage Current	0≤V _{IN} ≤5.5V	0 to 5.5	Room Full		±0.05	±0.1 ±1	μA
I _{OFF}	OFF State Leakage Current	0≤A, B≤V _{CC}	1.65 to 5.5	Room Full		±0.05	±0.1 ±1	μA
V _{IH}	Input High Voltage		1.65 to 2.3	Full	1.1			V
			2.3 to 2.7		1.4			
			2.7 to 3.6		1.8			
			3.6 to 4.3		2.1			
			4.3 to 5.5		2.6			
V _{IL}	Input Low Voltage		1.65 to 2.3	Full			0.4	V
			2.3 to 2.7				0.7	
			2.7 to 3.6				1.0	
			3.6 to 4.3				1.3	
			4.3 to 5.5				1.5	
I _{CC}	Quiescent Supply Current	V _{IN} =V _{CC} or GND I _O =0	5.5	Room Full			1.0 10	μA
R _{ON}	On-Resistance (Note 3)	V _{IN} =0V, I _O =30mA V _{IN} =2.4V, I _O =-30mA V _{IN} =4.5V, I _O =-30mA	4.5	Full		3.0 5.0 7.0	7.0 12 15	Ω
		V _{IN} =0V, I _O =24mA V _{IN} =3V, I _O =-24mA	3.0	Full		4.0 10	9.0 20	
		V _{IN} =0V, I _O =8mA V _{IN} =2.3V, I _O =-8mA	2.3	Full		5.0 13	12 30	
		V _{IN} =0V, I _O =4mA V _{IN} =1.65V, I _O =-4mA	1.65	Full		6.5 17	20 50	
R _{RANGE}	On Resistance Over Signal Range (Note 3, 7)	I _A =-30mA 0≤V _{Bn} ≤V _{CC}	4.5	Full			25	Ω
		I _A =-24mA 0≤V _{Bn} ≤V _{CC}	3.0	Full			50	
		I _A =-8mA, 0≤V _{Bn} ≤V _{CC}	2.3	Full			100	
		I _A =-4mA, 0≤V _{Bn} ≤V _{CC}	1.65	Full			300	
ΔR _{ON}	On Resistance Match Between Channels (Note 3, 4, 5)	I _A =-30mA, V _{Bn} =3.15V	4.5	Room		0.15		Ω
		I _A =-24mA, V _{Bn} =2.1V	3.0	Room		0.2		
		I _A =-8mA, V _{Bn} =1.6V	2.3	Room		0.5		
		I _A =-4mA, V _{Bn} =1.15V	1.65	Room		0.5		
R _{FLAT}	On Resistance Flatness (Note 3, 4, 6)	I _A =-30mA 0≤V _{Bn} ≤V _{CC}	5.0	Room		6.0		Ω
		I _A =-24mA 0≤V _{Bn} ≤V _{CC}	3.3	Room		12		
		I _A =-8mA, 0≤V _{Bn} ≤V _{CC}	2.5	Room		28		
		I _A =-4mA, 0≤V _{Bn} ≤V _{CC}	1.8	Room		125		

Electrical Characteristics (Continued)

Symbol	Parameter	Test Conditions	V _{CC} (V)	Temp	Limits (-40 °C to 85 °C)			Unit
					Min	Typ	Max	
AC Electrical Characteristics								
t _{PHL} t _{PLH}	Propagation Delay Bus to Bus (Note 9)	V _I =OPEN	1.65 to1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full			1.2 0.8 0.3	ns
t _{PZL} t _{PZH}	Output Enable Time Turn On Time (A to Bn)	V _I =2 ×V _{CC} for t _{PZL} V _I =0V for t _{PZH}	1.65 to1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full	7.0 3.5 2.5 1.7		24 14 7.6 5.7	ns
t _{PLZ} t _{PHZ}	Output Disable Time Turn Off Time (A Port to B Port)	V _I =2 ×V _{CC} for t _{PLZ} V _I =0V for t _{PHZ}	1.65 to1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full	3.0 2.0 1.5 0.8		13 7.5 5.3 3.8	ns
t _D	Break Before Make Time (Note 8)		1.65 to1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full	0.5 0.5 0.5 0.5			ns
Q _{INJ}	Charge Injection (Note 8)	C _L =0.1nF, V _{GEN} =0V, R _{GEN} =0Ω	5.0 3.3	Room		7.0 3.0		pC
O _{IRR}	Off Isolation (Note 10)	R _L =50Ω, f=10MHz	1.65 to 5.5	Room		-57		dB
Xtalk	Crosstalk	R _L =50Ω, f=10MHz	1.65 to 5.5	Room		-54		dB
BW	-3 dB Bandwidth	R _L =50Ω	1.65 to 5.5	Room		250		MHz
THD	Total Harmonic Distortion (Note 8)	R _L =600Ω 0.5V _{P-P} f=600Hz to 20kHz	5.0	Room		0.011		%
Capacitance								
C _{IN}	IN Pin Input Capacitance (Note 11)	V _{CC} =0V				2.3		pF
C _{IO-B}	B Port Off Capacitance (Note 11)	V _{CC} =5.0V				6.5		pF
C _{IOA-ON}	A Port Capacitance when Switch is Enabled (Note 11)	V _{CC} =5.0V				18.5		pF

Note 3: Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B Ports).

Note 4: Parameter is characterized but not tested in production.

Note 5: $\Delta R_{ON} = |R_{ON(B0)} - R_{ON(B1)}|$ measured at identical V_{CC}, temperature and voltage levels.

Note 6: Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.

Note 7: Guaranteed by design.

Note 8: Guaranteed by design.

Note 9: This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

Note 10: Off Isolation=20log₁₀ [V_A/V_{Bn}].

Note 11: T_A=+25 °C, f=1MHz, Capacitance is characterized but not tested in production.

Test Circuits/Timing Diagrams

NOTE: Input driven by 50 Ω source terminated in 50 Ω
 NOTE: C_L includes load and stray capacitance
 NOTE: Input PRR = 1.0 MHz; $t_W = 500$ ns

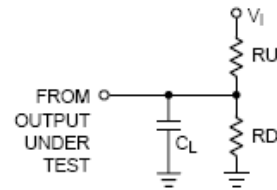


Figure 1 . AC Test Circuit

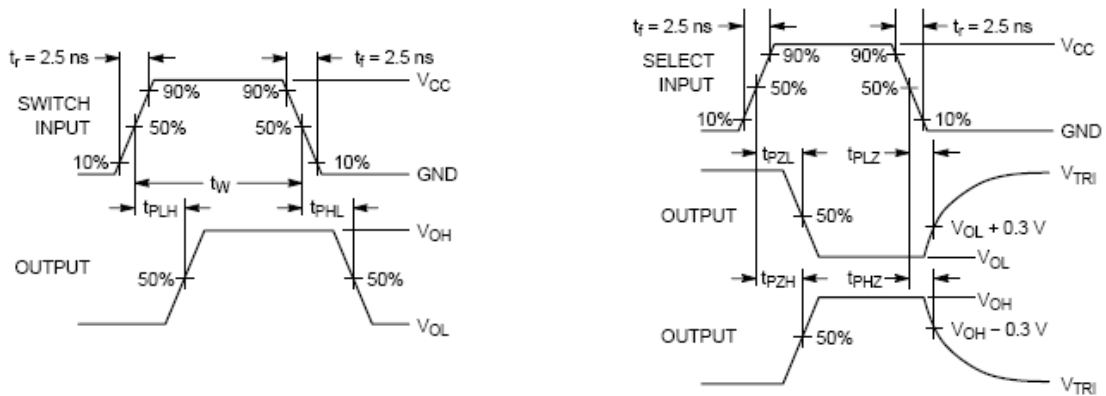
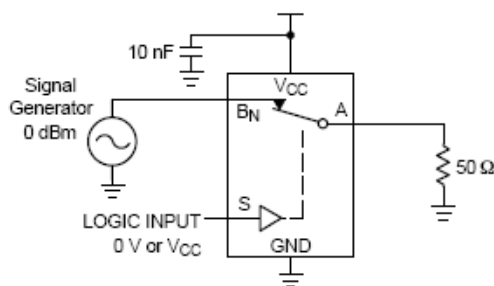
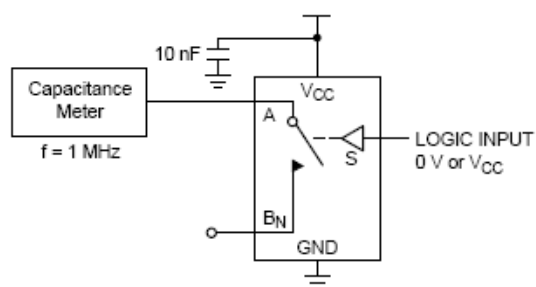
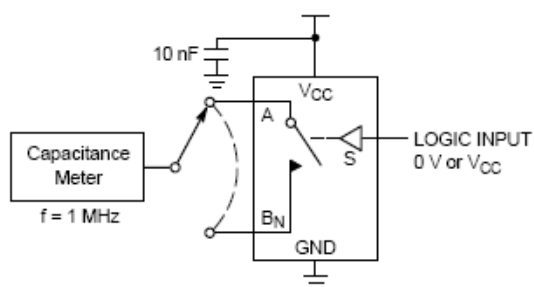
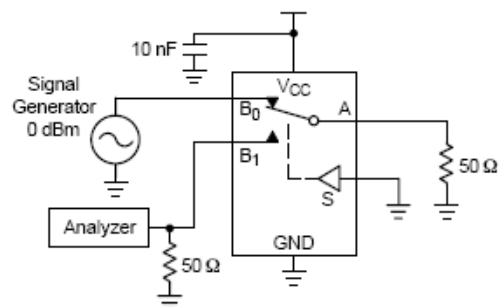
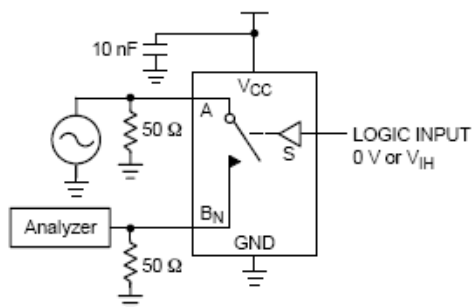
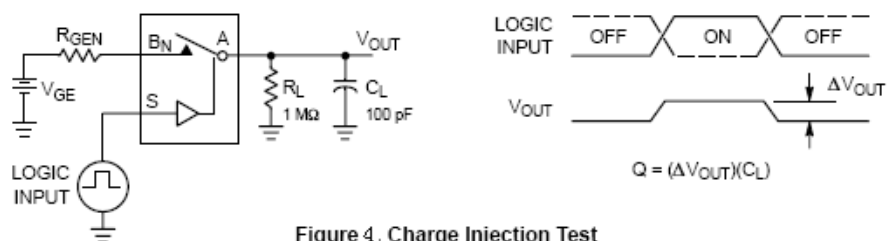


Figure 2 . AC Waveforms



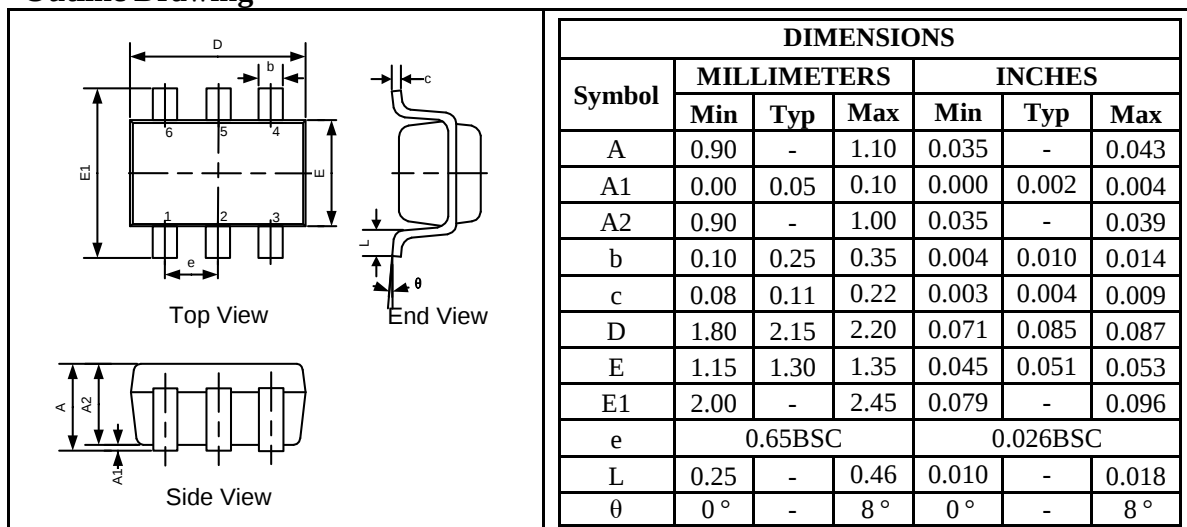
Figure 3 . Break Before Make Interval Timing



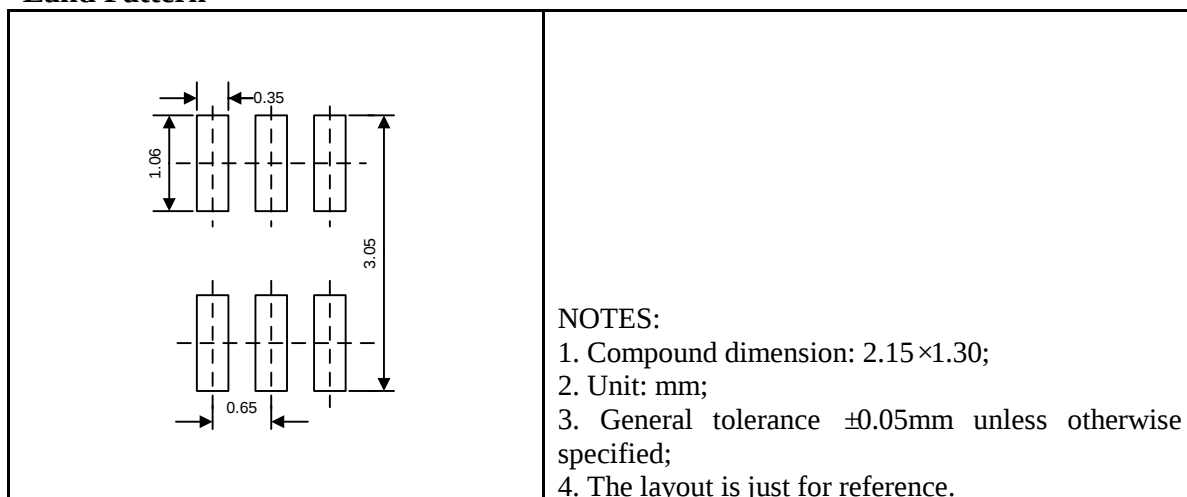
Package Information

UM3157 SC70-6/SC88/SOT363

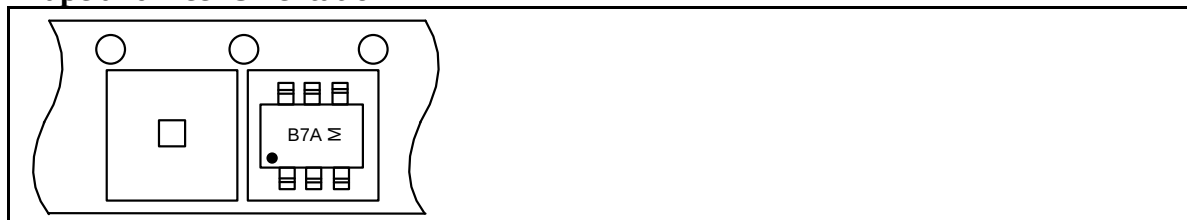
Outline Drawing



Land Pattern



Tape and Reel Orientation



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